

NCE N-Channel Super Trench II Power MOSFET

Description

The series of devices uses **Super Trench II** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS(ON)}}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

Application

- DC/DC Converter
- ●Ideal for high-frequency switching and synchronous rectification

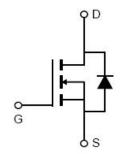
General Features

- V_{DS} =120V, I_D =130A $R_{DS(ON)}$ =4.5m Ω , typical (TO-220)@ V_{GS} =10V $R_{DS(ON)}$ =4.3m Ω , typical (TO-263)@ V_{GS} =10V
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!







Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP050N12	NCEP050N12	TO-220	-	-	-
NCEP050N12D	NCEP050N12D	TO-263	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	120	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	I _D	130	Α
Drain Current-Continuous(T _C =100°C)	I _D (100℃)	93	Α
Pulsed Drain Current	I _{DM}	520	Α
Maximum Power Dissipation	P _D	220	W
Derating factor		1.47	W/℃
Single pulse avalanche energy (Note 1)	Eas	1050	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	$^{\circ}$ C



NCEP050N12, NCEP050N12D

Thermal Characteristic

Thermal Resistance, Junction-to-Case	Rejc	0.68	°C/W	
memai resistance, ounction to ouse	1 1830	0.00	U C/ V V	П

Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Parameter Symbol Condition		Min	Тур	Max	Unit	
Off Characteristics				'			'
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA		120		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =120V,V _G	s=0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _D	s=0V	-	-	±100	nA
On Characteristics							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=2$	50µA	2.0	3.0	4.0	V
	_	.,	TO-220	-	4.5	5.0	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =65A	TO-263		4.3	5.0	mΩ
Forward Transconductance	g FS	V _{DS} =5V,I _D =6	65A	85	-	-	S
Dynamic Characteristics							
Input Capacitance	C _{lss}	V _{DS} =60V,V _{GS} =0V, F=1.0MHz		-	6880	-	PF
Output Capacitance	Coss			-	450	-	PF
Reverse Transfer Capacitance	C _{rss}			-	22	-	PF
Switching Characteristics (Note 2)							
Turn-on Delay Time	t _{d(on)}			-	20	-	nS
Turn-on Rise Time	t _r	V_{DD} =60V, I_{D} =65A		-	11.5	-	nS
Turn-Off Delay Time	t _{d(off)}	$V_{GS}=10V,R_{G}=$:1.6Ω	-	48	-	nS
Turn-Off Fall Time	t _f			-	10	-	nS
Total Gate Charge	Qg	.,	054	-	112	-	nC
Gate-Source Charge	Qgs	$V_{DS}=60V,I_{D}=$	·	-	36		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V		-	27		nC
Drain-Source Diode Characteristics				1			
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =6	65A	-		1.2	V
Diode Forward Current	Is			-	-	130	Α
Reverse Recovery Time	t _{rr}	$T_J = 25^{\circ}C, I_F = I_S$ di/dt = 100A/µs		-	76	-	nS
Reverse Recovery Charge	Qrr			_	150		nC

Notes:

^{1.} EAS condition : Tj=25 $^{\circ}\mathrm{C}$,V_DD=50V,V_G=10V,L=0.5mH,Rg=25 Ω

^{2.} Guaranteed by design, not subject to production

^{3.} These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsin k, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.



Typical Electrical and Thermal Characteristics

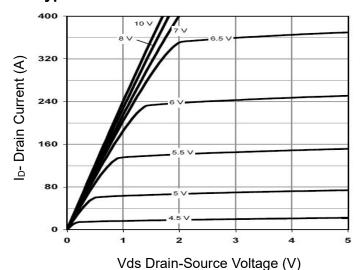
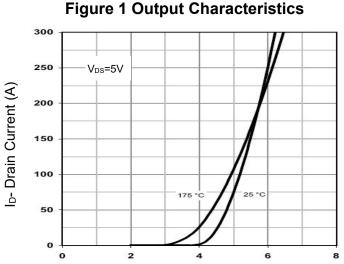
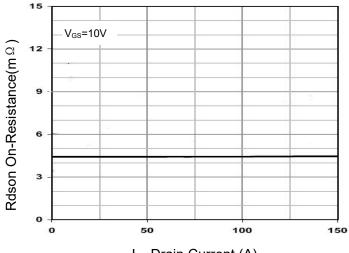


Figure 4 Output Characteristics

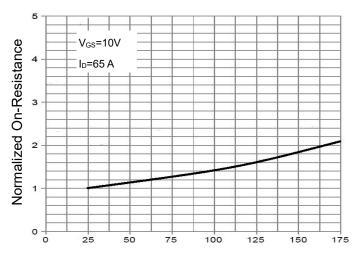


Vgs Gate-Source Voltage (V)
Figure 2 Transfer Characteristics



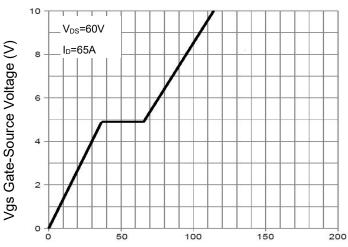
I_D- Drain Current (A)

Figure 3 Rdson- Drain Current



T_J-Junction Temperature(°C)

Figure 4 Rdson-Junction Temperature



Qg Gate Charge (nC)
Figure 5 Gate Charge

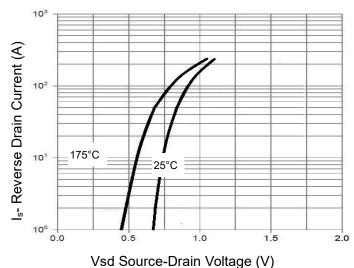


Figure 6 Source- Drain Diode Forward



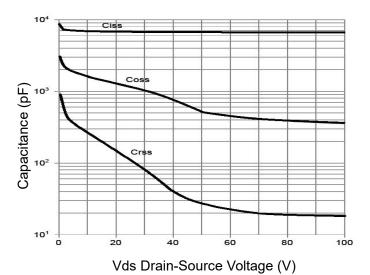


Figure 7 Capacitance vs Vds

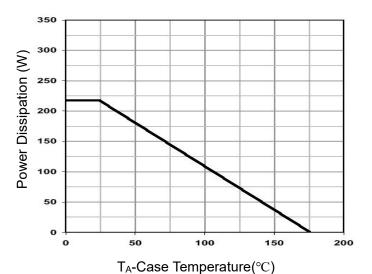


Figure 9 Power De-rating

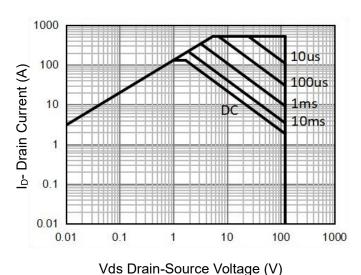


Figure 8 Safe Operation Area(Note 3)

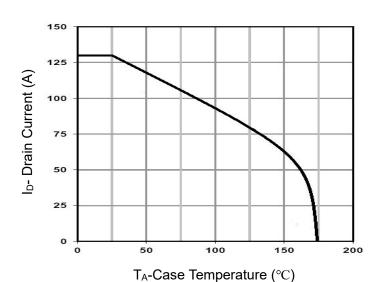
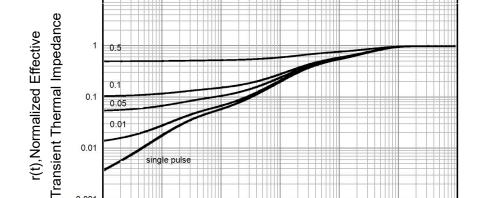


Figure 10 Current De-rating



0.00001

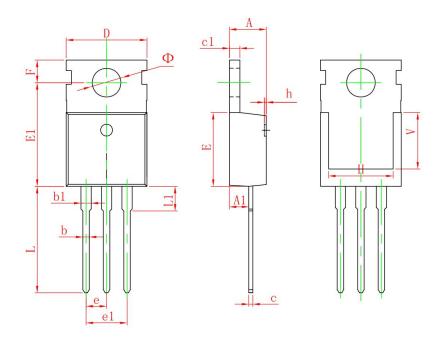
0.000001

on 0.0001 0.001 0.01 0. Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance



TO-220-3L Package Information

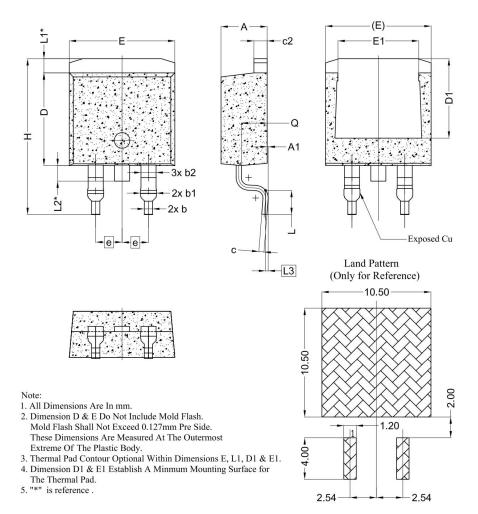


Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.950	9.750	0.352	0.384	
E1	12.650	13.050	0.498	0.514	
е	2.540	TYP.	0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	6.900 REF.		0.276	REF.	
Φ	3.400	3.800	0.134	0.150	

http://www.ncepower.com



TO-263-2L Package Information



SYMBOL	DIMENSIONS					
STMBOL	MIN.	NOM.	MAX.			
Α	4.24	4.44	4.64			
A1	0.00	0.10	0.25			
b	0.70	0.80	0.90			
b1	1.20	1.55	1.75			
b2	1.20	1.45	1.70			
С	0.40	0.50	0.60			
c2	1.15	1.27	1.40			
D	8.82	8.92	9.02			
D1 E	6.86	7.65	_			
	9.96	10.16	10.36			
E1	6.89 7.77		7.89			
е	2.54 BSC					
Н	14.61	15.00	15.88			
L	1.78	2.32	2.79			
L1	1.36 REF.					
L2		1.50 REF.				
L3	0.25 BSC					
Q	2.30	2.48	2.70			

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NCEP050N12, NCEP050N12D

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